



- 1.
- 2. PDFN5060 TO-252 SOP8
- 3.  $T_j(max) = 175$

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MOSFET P60V  
Qg Rdson  
MOS EAS

1. It adopts advanced process technology, featuring low internal resistance and excellent switching characteristics;
2. It adopts PDFN5060, TO-252, SOP8 and ok r,8

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New Product Launch